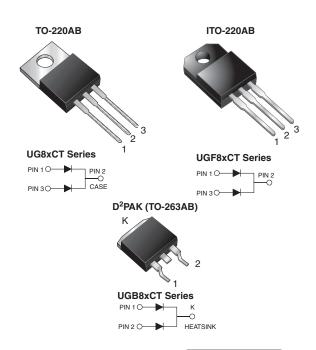
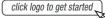
UG8xCT, UGF8xCT, UGB8xCT

Vishay General Semiconductor

Dual Common Cathode Ultrafast Plastic Rectifier





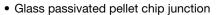




PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 4.0 A				
V_{RRM}	500 V to 600 V				
I _{FSM} 65 A					
t _{rr}	25 ns				
V_F at $I_F = 4$ A	1.50 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration Common cathode					

FEATURES

Power pack





- · Ultrafast recovery time
- · Soft recovery characteristics
- · Low switching losses, high efficiency
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max., 10 s per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified (for ITO-220AB and TO-263AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high voltage and high frequency power factor corrector, freewheeling diodes and secondary DC/DC rectification application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG8HCT	UG8JCT	UNIT		
Max. repetitive peak reverse voltage	V _{RRM}	500	600	V		
Max. working reverse voltage	V _{RWM}	400	480	V		
Max. RMS voltage	V _{RMS}	350	420	V		
Max. DC blocking voltage	V_{DC}	500	600	V		
Max. average forward rectified current	I _{F(AV)}	8.0		Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	65		Α		
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150		°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink, t = 1 min	V _{AC}	1500		V		

UG8xCT, UGF8xCT, UGB8xCT

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	UG8HCT	UG8JCT	UNIT	
Max. instantaneous forward voltage per diode (1)	I _F = 4 A T _J = 25 °C		VF	1.75		V	
Max. Instantaneous forward voltage per diode (%	I _F = 4 A	T _J = 125 °C	VF	1.50		7 °	
		T _J = 25 °C		30		μΑ	
Max. DC reverse current per diode at V_{RWM}		T _J = 100 °C	I _R	800		μΑ	
		T _J = 125 C		4		mA	
Max. reverse recovery time per diode	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	25		ns	
Max. reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	5	0	ns	
Typical softness factor (t _b /t _a)	$I_F = 4.0 \text{ A}, I_{rr} = 0.1 \text{ I}_{RM}$ $I_F = 4.0 \text{ A}, \text{ dI/dt} = 240 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}, I_{rr} = 0.1 \text{ I}_{RM}$		S	0.9		-	
Max. reverse recovery current per diode	I _F = 4.0 A, dl/dt = 32 A/μs, V _R = 400 V, T _C = 125 °C		I _{RM}	3.0		Α	
Max. reverse recovery current per diode	$I_F = 4.0 \text{ A}, \text{ dI/dt} = 240 \text{ A/}\mu\text{s}, \\ V_R = 400 \text{ V}, T_C = 125 ^{\circ}\text{C}$		I _{RM}	8	.0	Α	
Peak forward recovery time per diode	$I_F = 4.0 \text{ A}, \text{ dI/dt} = 64 \text{ A/}\mu\text{s},$ $V_F = 1.1 \text{ V}_{F \text{ max}}.$		t _{fr}	50	00	ns	

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UG8	UGF8	UGB8	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	3.5	6.0	3.5	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	UG8JCT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	UGF8JCT-E3/45	2.00	45	50/tube	Tube		
TO-263AB	UGB8JCT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	UGB8JCT-E3/81	1.35	81	800/reel	Tape and reel		
ITO-220AB	UGF8JCTHE3/45 (1)	2.00	45	50/tube	Tube		
TO-263AB	UGB8JCTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	UGB8JCTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified, available in ITO-220AB and TO-263AB package

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

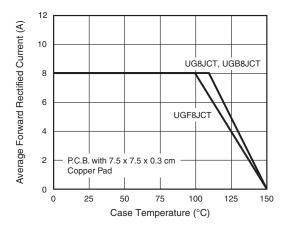
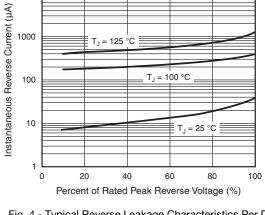


Fig. 1 - Max. Forward Current Derating Curve



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Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

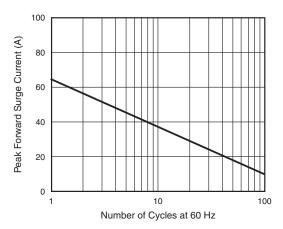


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

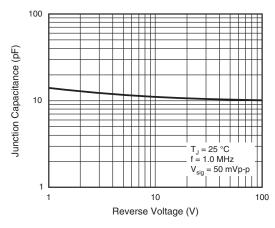


Fig. 5 - Typical Junction Capacitance Per Diode

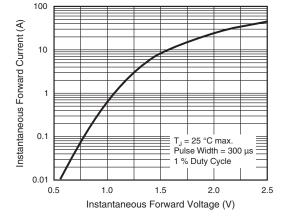


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

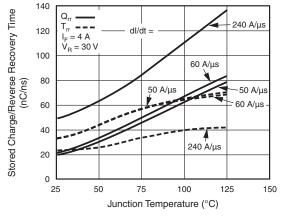
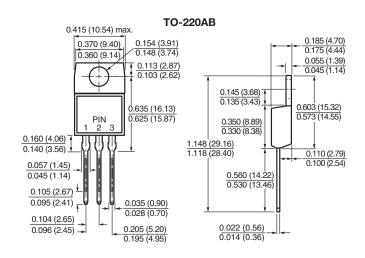


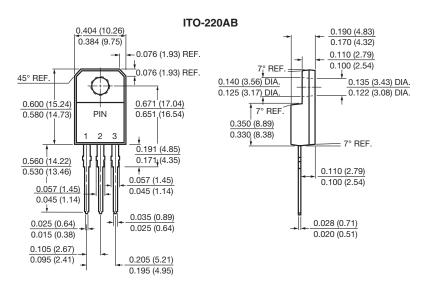
Fig. 6 - Reverse Switching Characteristics Per Diode

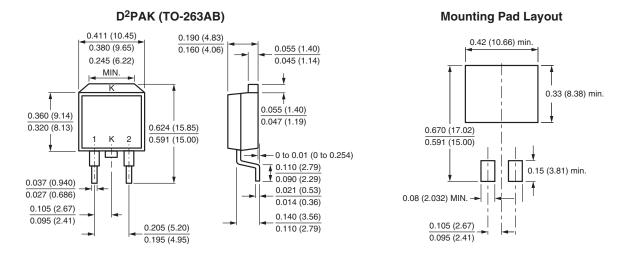


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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